

## **BUK9Y13-60EL**

Single N-channel 60 V, 7.9 mOhm logic level MOSFET in LFPAK56 using Enhanced SOA technology 20 April 2022

Product data sheet

## 1. General description

Single, logic level, N-channel MOSFET in LFPAK56 using Application specific (ASFET) Enhanced SOA technology. This product has been designed and qualified to AEC-Q101 for use in linear mode in airbag applications.

## 2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
- Enhanced SOA technology for improved linear mode performance
- LFPAK copper clip package technology:
  - · High robustness and current handling capability
  - Gull wing leads for easy AOI inspection and exceptional board level reliability •

## 3. Applications

- 12 V automotive systems
- Airbag squib voltage regulator MOSFET

## 4. Quick reference data

#### Table 1 Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	60	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	90	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	147	W
Static chara	acteristics			-	_		
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 25 °C; Fig. 13		4.4	6.3	7.9	mΩ
Dynamic ch	naracteristics	·					
Q <sub>GD</sub>	gate-drain charge	$\label{eq:ID} \begin{array}{l} I_D = 20 \text{ A}; \ V_{DS} = 48 \text{ V}; \ V_{GS} = 4.5 \text{ V}; \\ T_j = 25 \ ^\circ\text{C}; \ \overline{\text{Fig. 15}}; \ \overline{\text{Fig. 16}} \end{array}$		-	11.7	23.3	nC

90 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, [1] thermal design and operating temperature.

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## 5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	
2	S	source		D
3	S	source	a	
4	G	gate		G_(FA)
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	mbb076 S

## 6. Ordering information

#### Table 3. Ordering information

Type number			
	Name	Description	Version
BUK9Y13-60EL	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK9Y13-60EL	91360EL

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

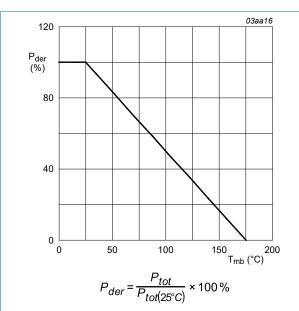
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	60	V
V <sub>GS</sub>	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-10	10	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	147	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	90	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>		-	64	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}$ C; <u>Fig. 3;</u> Fig. 4		-	361	A
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drai	n diode					
Is	source current	T <sub>mb</sub> = 25 °C		-	90	А
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	361	A
Avalanche r	uggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$ \begin{split} &I_{D} = 49.7 \text{ A}; \ &V_{sup} \leq \ 60 \ V; \ &R_{GS} = 50 \ \Omega; \\ &V_{GS} = 10 \ V; \ &T_{j(init)} = 25 \ ^{\circ}C; \ unclamped; \\ &t_{p} = 62 \ \mu s; \ &Fig. \ 5 \end{split} $	[2] [3]	-	127	mJ

Symbol	Parameter	Conditions		Min	Max	Unit
I <sub>AS</sub>		$V_{sup} \le 60 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; Fig. 5$	[2] [3] [4]	-	49.7	A

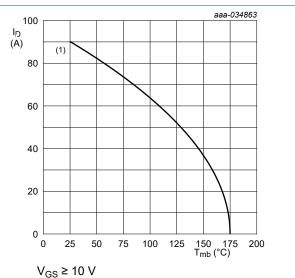
[1] 90 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

- [3] Refer to application note AN10273 for further information.
- [4] Protected by 100% test.

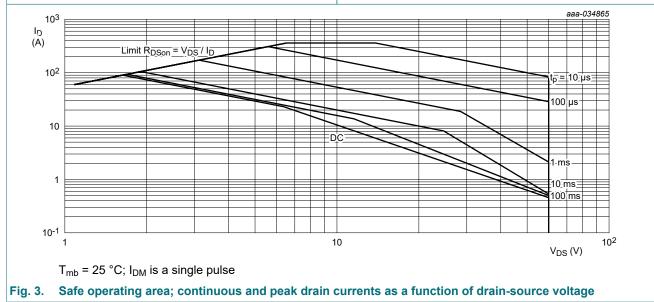


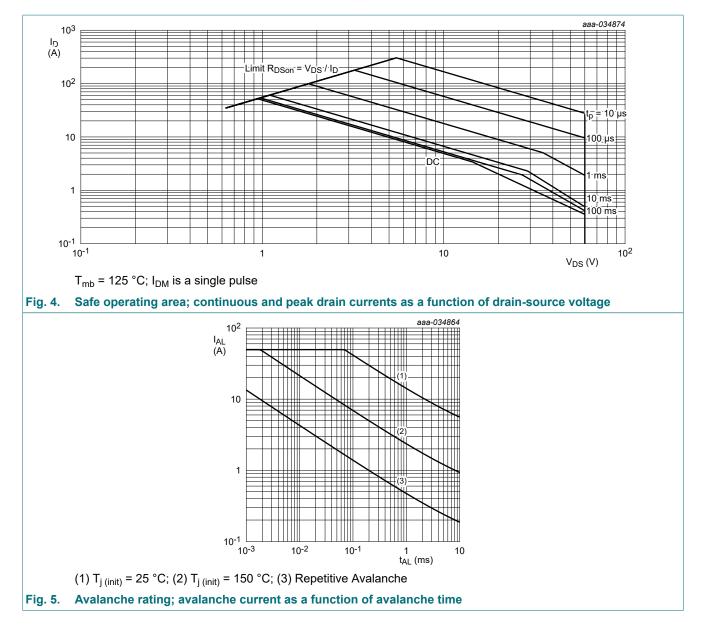




(1) 90 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

## Fig. 2. Continuous drain current as a function of mounting base temperature

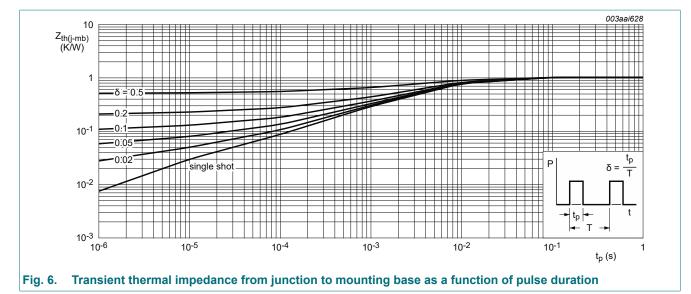




### 9. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	0.92	1.02	K/W

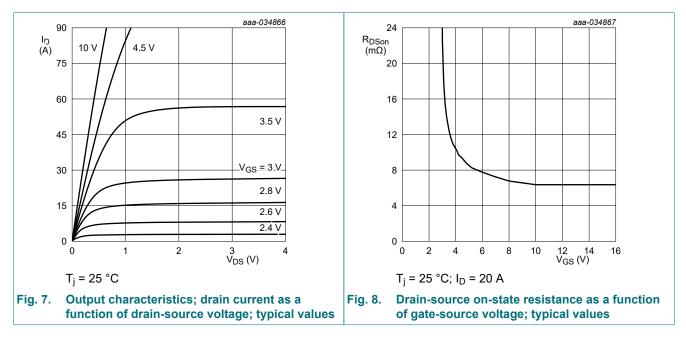


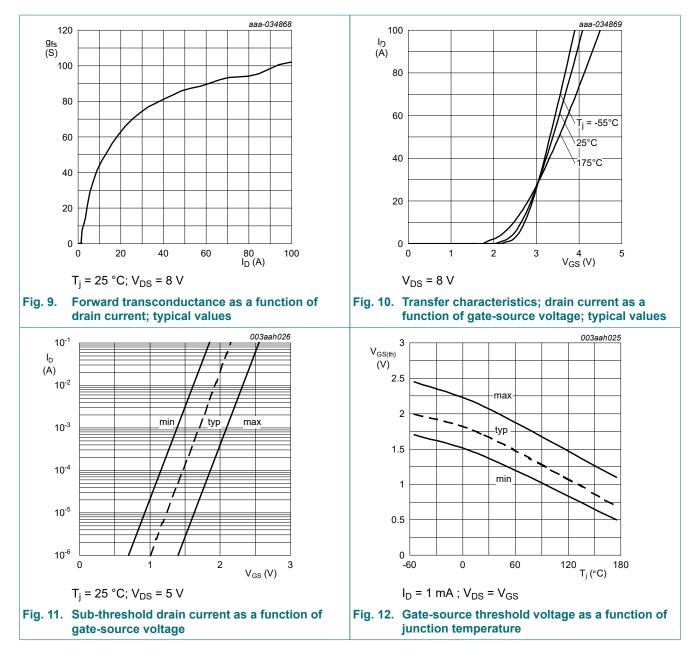
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	·	- I			
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	60	66	-	V
	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -40 °C	-	61.9	-	V
		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	54	61	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C}; Fig. 11;$ Fig. 12	1.4	1.78	2.1	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}; Fig. 12$	-	-	2.45	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 12	0.5	-	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.015	1	μA
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	54	500	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 25 °C; Fig. 13	4.4	6.3	7.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 105 °C; <u>Fig. 14</u>	6.7	10	12.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 125 °C; Fig. 14	7.4	11	14.3	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 175 °C; Fig. 14	9.2	13.8	18.2	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 25 °C; Fig. 13	6.5	9.3	12.4	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 105 °C; Fig. 14	9.6	14.3	19.7	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 125 °C; Fig. 14	10.5	15.7	21.8	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 175 °C; Fig. 14	12.8	19.4	27.4	mΩ

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C		-	2.01	-	Ω
Dynamic ch	naracteristics						
Q <sub>G(tot)</sub>	total gate charge	$    I_D = 20 \text{ A}; \text{ V}_{DS} = 48 \text{ V}; \text{ V}_{GS} = 4.5 \text{ V}; \\     T_j = 25 \text{ °C}; \text{ Fig. 15}; \text{ Fig. 16} $		-	28	39.5	nC
		$\label{eq:ID} \begin{array}{l} I_D = 20 \text{ A}; \ V_{DS} = 48 \text{ V}; \ V_{GS} = 10 \text{ V}; \\ T_j = 25 \ ^\circ\text{C}; \ \overline{\text{Fig. 15}}; \ \overline{\text{Fig. 16}} \end{array}$		-	58	81	nC
Q <sub>GS</sub>	gate-source charge	$T_{j} = 25 \text{ °C}; \ \overline{\text{Fig. 15}}; \ \overline{\text{Fig. 16}}$ $I_{D} = 20 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 4.5 \text{ V};$ $T_{j} = 25 \text{ °C}; \ \overline{\text{Fig. 15}}; \ \overline{\text{Fig. 16}}$ $V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; \ f = 1 \text{ MHz};$ $T_{j} = 25 \text{ °C}; \ \overline{\text{Fig. 17}}$		-	8.2	12.3	nC
Q <sub>GD</sub>	gate-drain charge			-	11.7	23.3	nC
C <sub>iss</sub>	input capacitance	$T_j = 25 \text{ °C}; \frac{Fig. 17}{}$		-	3229	4520	pF
C <sub>oss</sub>	output capacitance			-	301	361	pF
C <sub>rss</sub>	reverse transfer capacitance			-	156	213	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 48 \text{ V}; \text{ R}_{L} = 2.4 \Omega; \text{ V}_{GS} = 5 \text{ V};$ $\text{R}_{G(ext)} = 5 \Omega; \text{ T}_{j} = 25 \text{ °C}$		-	16	-	ns
t <sub>r</sub>	rise time			-	39	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	34	-	ns
t <sub>f</sub>	fall time	-		-	29	-	ns
9fs	transfer conductance	V <sub>DS</sub> = 8 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	62.5	-	S
Source-drai	in diode						
V <sub>SD</sub>	source-drain voltage	$I_{S}$ = 20 A; $V_{GS}$ = 0 V; $T_{j}$ = 25 °C; <u>Fig. 18</u>		-	0.82	1	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	28	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C; <u>Fig. 19</u>	[1]	-	30	-	nC

[1] includes capacitive recovery





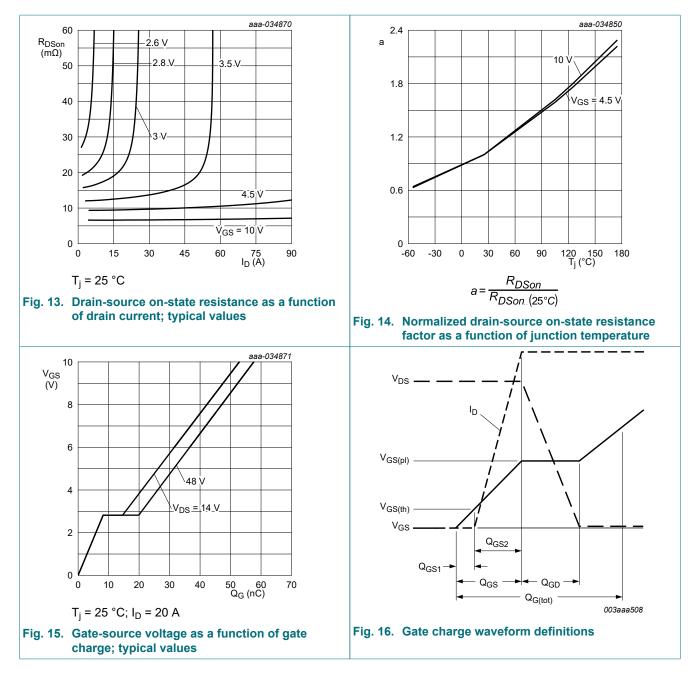
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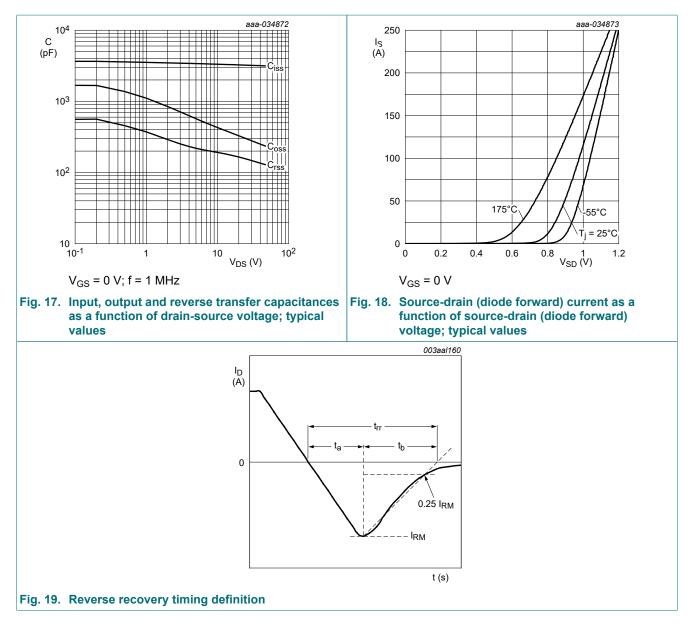
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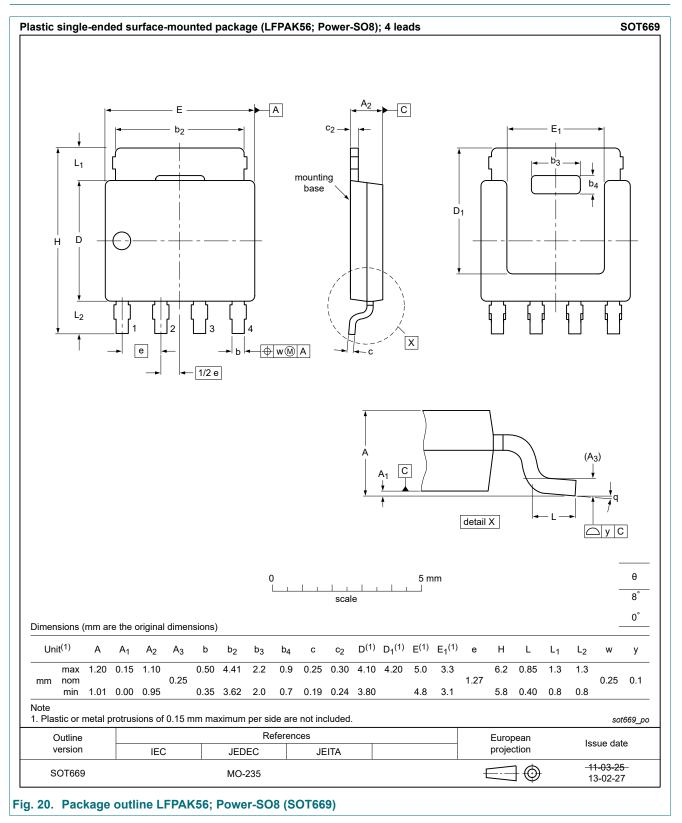
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## **BUK9Y13-60EL**

Single N-channel 60 V, 7.9 mOhm logic level MOSFET in LFPAK56 using Enhanced SOA technology



## 11. Package outline



## 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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